## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:
Wen Chin Lin, et al.

Serial No.: 10/678,699

Examiner: Nguyen, Dang T.

Filed: October 3, 2003

For: Multi-Sensing Level MRAM
Structure with Different
Magneto-Resistance Ratios

Attorney Docket No.: 2002-1078 / 24061.32

Serial No.: 2002-1078 / 24061.32

Examiner: Nguyen, Dang T.

Confirmation No.: 9863

Commissioner for Patents Mail Stop Amendment P.O. Box 1450 Alexandria, VA 22313-1450

## RESPONSE TO NON-FINAL OFFICE ACTION MAILED JULY 20, 2006

The present paper is submitted in response to the Non-Final Office Action of July 20, 2006. No fees, including extension of time fees, are believed necessary for consideration of the present paper. However, if any fees are necessary, including extension of time fees, the extension of time is hereby requested, and the Commissioner is hereby authorized to charge any fees, including those for the extension of time, to Haynes and Boone, LLP's Deposit Account No. 08-1394.

Amendments to the Claims are shown in the listing of claims beginning on page 2 of this paper.

Remarks/Arguments begin on page 7 of this paper.